

Notice of References Cited	Application/Control No. 10/766,920		Applicant(s)/Patent Under Reexamination NOLAN, THOMAS PATRICK	
	Examiner Holly Rickman		Art Unit 1773	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-2006/0024530 A1	02-2006	Nolan, Thomas Patrick	428/827
*	B	US-2006/0002026 A1	01-2006	Stipe et al.	360/135
*	C	US-2005/0134988 A1	06-2005	Nakamura et al.	360/055
*	D	US-6,936,353 B1	08-2005	Wu et al.	428/611
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Chen et al., Effect of Pt buffer layer on structural and magnetic properties of FePt thin films, J Appl Phys, Vol. 93, No. 3, February 2003, pp. 1661-1665
	V	Gao et al., Magnetic recording configuration for densities beyond 1 Tb/in ² and data rates beyond 1 Gb/s, IEEE, Trans Magn, Vol. 38, No. 6, Nov 2002, pp 3675-3683
	W	Jeong et al., Controlling the crystallographic orientation in ultrathin L1- FePt (111) films on MgO(111) underlayer, IEEE Trans Magn, Vol. 37, No. 4, July 2001, pp 1268-1270
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.